# BLA9H0912L-1200P; BLA9H0912LS-1200P(G) LDMOS avionics power transistor

AMPLEON Product data sheet

#### **Product profile** 1.

### 1.1 General description

1200 W LDMOS power transistor for avionics applications in the frequency range of 960 MHz to 1215 MHz.

#### **Typical performance** Table 1.

Typical RF performance at  $T_{case} = 25$  °C;  $t_p = 50 \ \mu s$ ;  $\delta = 2$  %;  $I_{Dq} = 75 \ mA$ ; in a class-AB demo circuit.

Test signal	f	V <sub>DS</sub>	PL	G <sub>p</sub>	η <sub>D</sub>
	(MHz)	(V)	(W)	(dB)	(%)
pulsed RF	1030	50	1200	19	60
pulsed RF at 1 dB compression	960 to 1215	50	>1050	19	57

### 1.2 Features and benefits

- High efficiency
- Excellent ruggedness
- Designed for avionics band operation
- Excellent thermal stability
- Easy power control
- Integrated dual sided ESD protection enables excellent off-state isolation
- High flexibility with respect to pulse formats
- Internally matched for ease of use
- For RoHS compliance see the product details on the Ampleon website

### 1.3 Applications

Avionics applications in the frequency range of 960 MHz to 1215 MHz

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# BLA9H0912L(S)-1200P(G)

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# 2. Pinning information

Pin	Description	Simplified outlin	e Graphic symbol
BLA9H09	12L-1200P (SOT539A)		
1	drain1		
2	drain2		
3	gate1		
4	gate2	3 4	3
5	source	[1]	
BLA9H09	12LS-1200P (SOT539B)		sym117
1	drain1		
2	drain2		
3	gate1		
4	gate2	3 4	3 5
5	source	[1]	4 <b>+</b> 2 sym117
BLA9H09	12LS-1200PG (SOT1248C)		
1	drain1	4	1
2	drain2		
3	gate1		5 3
4	gate2	3 4	4 - 1 - 5
5	source	[1]	2 sym117

# 3. Ordering information

Table 3.	Ordering information
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Type number	Packag	ge de la companya de				
	Name	Description	Version			
BLA9H0912L-1200P	-	flanged balanced ceramic package; 2 mounting holes; 4 leads	SOT539A			
BLA9H0912LS-1200P	-	earless flanged balanced ceramic package; 4 leads	SOT539B			
BLA9H0912LS-1200PG	-	earless flanged LDMOST ceramic package; 4 leads	SOT1248C			

# 4. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	-	106	V
V <sub>GS</sub>	gate-source voltage	-6	+11	V
T <sub>stg</sub>	storage temperature	-65	+150	°C
Tj	junction temperature [1]	-	225	°C

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

# 5. Thermal characteristics

Table 5.	Thermal characteristics			
Symbol	Parameter	Conditions	Тур	Unit
Z <sub>th(j-mb)</sub>	transient thermal impedance from junction	$T_{case} = 85 \text{ °C}; P_L = 1200 \text{ W}$		
	to mounting base	$t_p = 32 \ \mu s; \ \delta = 2 \ \%$	0.027	K/W
		$t_p = 10 \ \mu s; \ \delta = 10 \ \%$	0.036	K/W
		$t_p = 64 \ \mu s; \ \delta = 1 \ \%$	0.032	K/W
		$t_p$ = 2.4 ms; $\delta$ = 6.4 %	0.126	K/W

# 6. Characteristics

#### Table 6. DC characteristics

 $T_i = 25 \ ^{\circ}C$ , per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$V_{GS} = 0 V; I_{D} = 4 mA$	106	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 400 mA	1.5	2.0	2.5	V
I <sub>DSS</sub>	drain leakage current	$V_{GS} = 0 V; V_{DS} = 50 V$	-	-	2.8	μΑ
I <sub>DSX</sub>	drain cut-off current	$\label{eq:VGS} \begin{split} V_{GS} &= V_{GS(th)} + 3.75 \; V; \\ V_{DS} &= 10 \; V \end{split}$	-	60	-	A
I <sub>GSS</sub>	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	280	nA
<b>g</b> fs	forward transconductance	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 400 mA	-	3.7	-	S
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ I <sub>D</sub> = 14 A	-	0.060	-	Ω

### Table 7. RF characteristics

Test signal: pulsed RF; f = 1030 MHz;  $t_p = 50 \ \mu$ s;  $\delta = 2 \ \%$ ; RF performance at  $V_{DS} = 50 \ V$ ;  $I_{Dq} = 75 \ m$ A;  $T_{case} = 25 \ ^{\circ}$ C; unless otherwise specified, in a class-AB production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G <sub>p</sub>	power gain	P <sub>L</sub> = 1200 W	17.8	19	-	dB
η <sub>D</sub>	drain efficiency	P <sub>L</sub> = 1200 W	57	60	-	%
RL <sub>in</sub>	input return loss	P <sub>L</sub> = 1200 W	-	–15	-	dB
P <sub>droop(pulse)</sub>	pulse droop power	P <sub>L</sub> = 1200 W	-	0.2	0.5	dB

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#### Table 7. RF characteristics ... continued

Test signal: pulsed RF; f = 1030 MHz;  $t_p$  = 50  $\mu$ s;  $\delta$  = 2 %; RF performance at V<sub>DS</sub> = 50 V; I<sub>Dq</sub> = 75 mA; T<sub>case</sub> = 25 °C; unless otherwise specified, in a class-AB production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t <sub>r</sub>	rise time	P <sub>L</sub> = 1200 W	-	6	50	ns
t <sub>f</sub>	fall time	P <sub>L</sub> = 1200 W	-	6	50	ns
P <sub>L(2dB)</sub>	output power at 2 dB gain compression		-	1400	-	W

# 7. Test information

### 7.1 Ruggedness in class-AB operation

The BLA9H0912L-1200P, BLA9H0912LS-1200P and BLA9H0912LS-1200PG are capable of withstanding a load mismatch corresponding to VSWR = 20 : 1 through all phases under the following conditions: V<sub>DS</sub> = 50 V; I<sub>Dq</sub> = 75 mA; P<sub>L</sub> = 1200 W; t<sub>p</sub> = 50  $\mu$ s;  $\delta$  = 2 %.

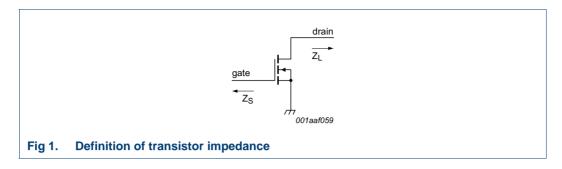
### 7.2 Impedance information

Table 8.         Typical impedance (per section)				
f	Z <sub>S</sub> [1]	Z <sub>L</sub> [1]		
(MHz)	(Ω)	(Ω)		
BLA9H0912L-1200P; BLA9H09	12LS-1200P			
950	0.717 – j1.793	0.965 – j1.305		
1000	0.953 – j1.886	1.049 – j1.561		
1050	1.091 – j1.910	1.032 – j1.780		
1100	1.353 – j0.443	1.291 – j1.952		
1150	1.962 – j1.061	1.474 – j2.081		
1200	0.837 – j0.936	1.514 – j2.413		
BLA9H0912LS-1200PG				
950	0.864 – j4.192	1.114 – j3.604		
1000	1.168 – j4.414	1.249 – j4.020		
1050	1.354 – j4.560	1.267 – j4.411		
1100	1.481 – j2.963	1.625 – j4.718		
1150	2.274 – j3.655	1.901 – j4.980		
1200	1.097 – j3.801	2.087 – j5.532		

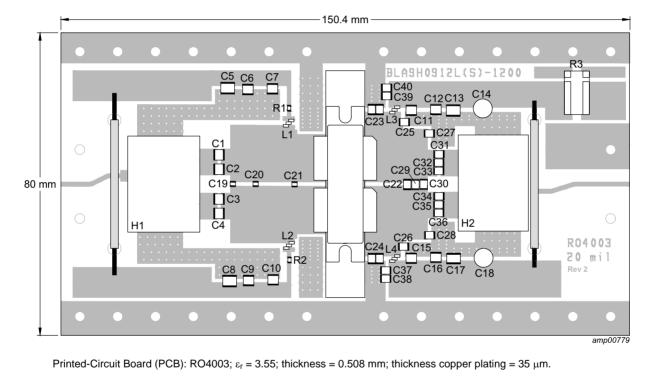
[1]  $Z_S$  and  $Z_L$  defined in Figure 1.

BLA9H0912L-1200P\_LS-1200P\_LS-1200PG

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### 7.3 Test circuit



See Table 9 for a list of components.

### Fig 2. Component layout for application circuit

### Table 9. List of components

### See Figure 2 for component layout.

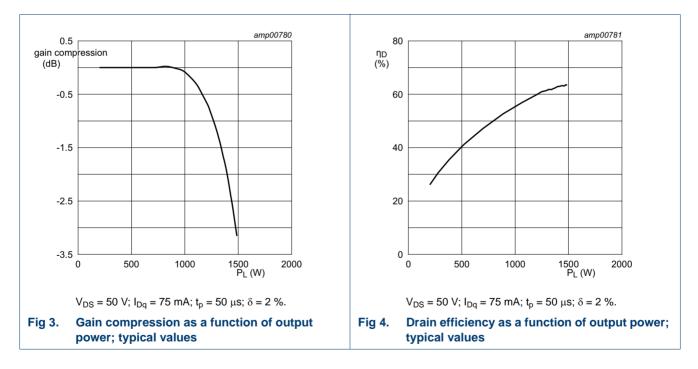
Component	Description	Value	Remarks
C1, C2, C3, C4	multilayer ceramic chip capacitor	39 pF	ATC 100B
C5, C8, C13, C17	multilayer ceramic chip capacitor	10 μF	Murata: GRM55DR61H106KA88L
C6, C9, C12, C16	multilayer ceramic chip capacitor	1 nF	ATC 100B
C7, C10, C11, C15	multilayer ceramic chip capacitor	51 pF	ATC 100B
C14, C18	electrolytic capacitor	100 μF, 63 V	
C19, C20	multilayer ceramic chip capacitor	0.5 pF	ATC 100A
C21	multilayer ceramic chip capacitor	5.6 pF	ATC 100A
C22	multilayer ceramic chip capacitor	3.0 pF	ATC 100B

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### Table 9. List of components ...continued

Component	Description	Value	Remarks
C23a, C23b, C24a, C24b	multilayer ceramic chip capacitor	5.1 pF	ATC 800B
C25, C26, C27, C28	multilayer ceramic chip capacitor	2.4 pF	ATC 100B
C29	multilayer ceramic chip capacitor	0.8 pF	ATC 100B
C30	multilayer ceramic chip capacitor	1.6 pF	ATC 100B
C31, C32, C33, C34, C35, C36	multilayer ceramic chip capacitor	43 pF	ATC 100B
C37, C39	multilayer ceramic chip capacitor	20 nF	ATC 200B
C38, C40	multilayer ceramic chip capacitor	1 nF	ATC 200B
H1, H2	balun transformer		Anaren: 3A412S
L1, L2	inductor	27 nH	Coilcraft: 1111SQ-27NJEB
L3, L4	inductor	1/2 turns, D = 1.5 mm, 8.9 nH	8 mm copper wire
R1, R2	resistor	5 Ω	SMD 0603
R3	resistor	$5 \text{ m}\Omega$	FC4L110R005FER

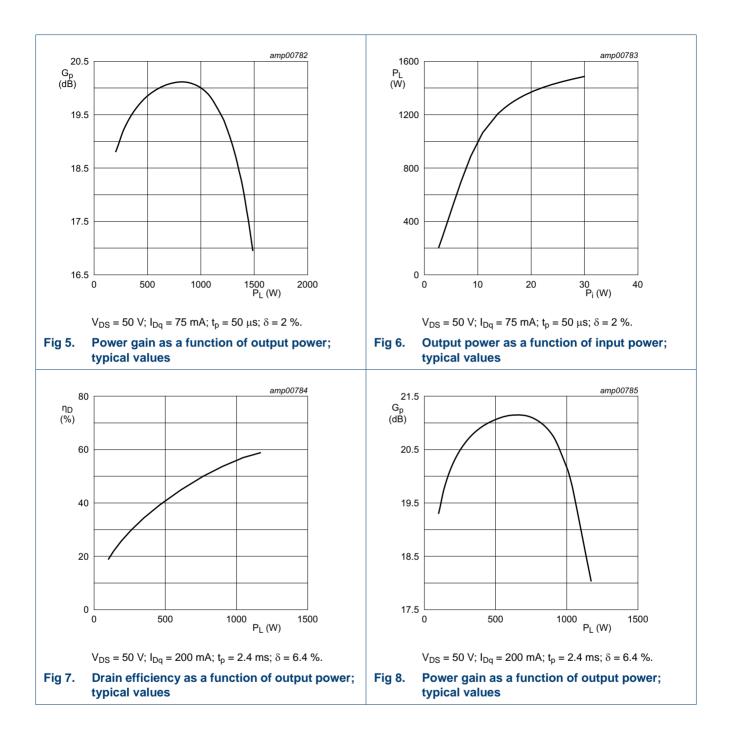
# 7.4 Graphical data



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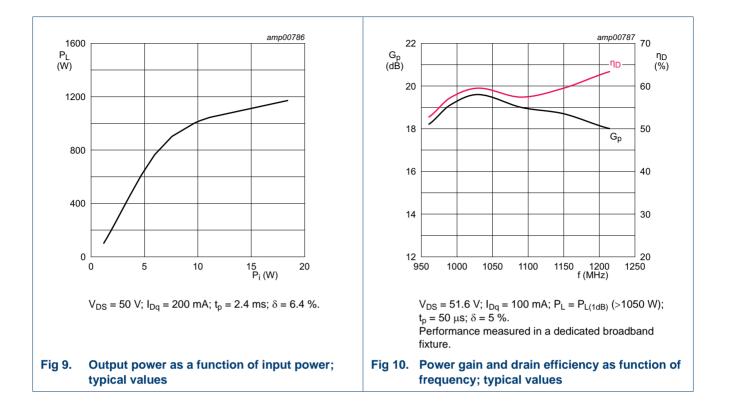
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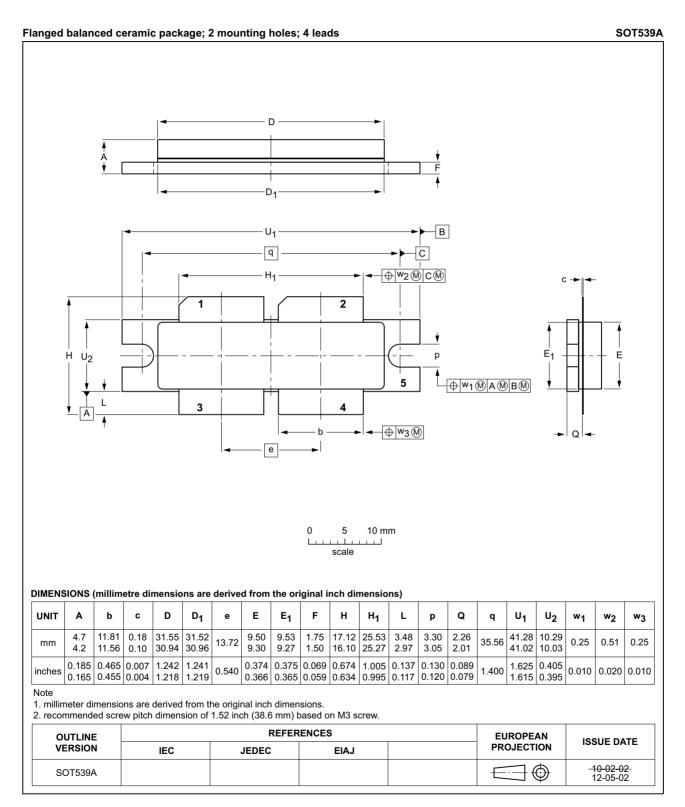
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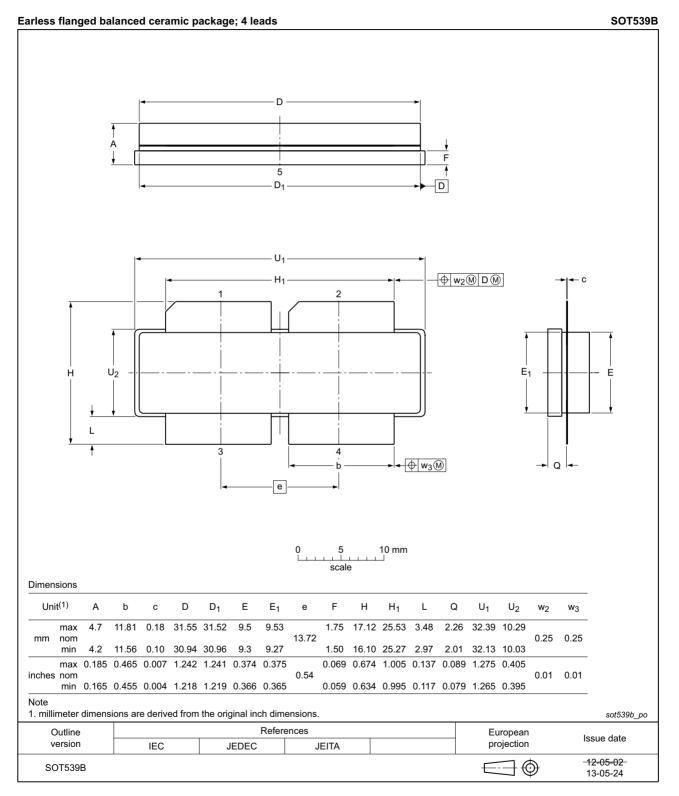
### LDMOS avionics power transistor

# 8. Package outline



### Fig 11. Package outline SOT539A

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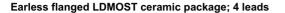


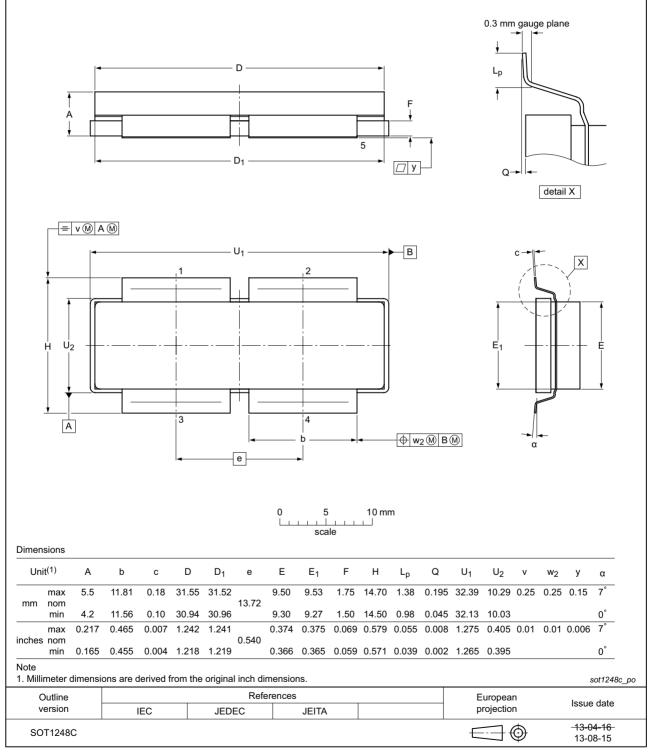
### Fig 12. Package outline SOT539B

BLA9H0912L-1200P\_LS-1200P\_LS-1200PG

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SOT1248C





### Fig 13. Package outline SOT1248C

# 9. Handling information

#### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

### Table 10.ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 [2]

[1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V.

[2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V.

# **10. Abbreviations**

Table 11. Abbreviations				
Acronym	Description			
ESD	ElectroStatic Discharge			
LDMOS	Laterally Diffused Metal-Oxide Semiconductor			
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor			
MTF	Median Time to Failure			
RoHS	Restriction of Hazardous Substances			
SMD	Surface Mounted Device			
VSWR	Voltage Standing Wave Ratio			

# 11. Revision history

#### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLA9H0912L-1200P_LS-1200P_LS- 1200PG v.2	20230110	Product data sheet	-	BLA9H0912L-1200P_LS- 1200P v.1
Modifications:	<u>Table 2 on page 2</u> : added BLA9H0912LS-1200PG			
	<ul> <li><u>Table 3 on page 2</u>: added BLA9H0912LS-1200PG</li> </ul>			
	<ul> <li><u>Table 5 on page 3</u>: changed P<sub>L</sub> value from 600 W to 1200 W</li> </ul>			
	<ul> <li>Section 7.1 on page 4: added BLA9H0912LS-1200PG</li> </ul>			
	• <u>Table 8 on page 4</u> : updated table			
<ul> <li>Figure 13 on page 11: added figure of package of</li> </ul>				e SOT1248C
	<u>Section 12.2 on page 13</u> : updated section			
	Section 12.3	3 on page 13: updated	section	
BLA9H0912L-1200P_LS-1200P v.1	20181101	Product data sheet	-	-

# **12. Legal information**

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Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
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### LDMOS avionics power transistor

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